

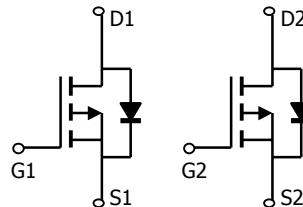
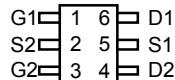


## AO6801

### Dual P-Channel Enhancement Mode Field Effect Transistor

General Description	Features
<p>The AO6801 uses advanced trench technology to provide excellent <math>R_{DS(ON)}</math> and low gate charge. This device is suitable for use as a load switch or in PWM applications.</p>	<p><math>V_{DS}</math> (V) = -30V  <math>I_D</math> = -2.3 A  <math>R_{DS(ON)} &lt; 135\text{m}\Omega</math> (<math>V_{GS} = -10\text{V}</math>)  <math>R_{DS(ON)} &lt; 185\text{m}\Omega</math> (<math>V_{GS} = -4.5\text{V}</math>)  <math>R_{DS(ON)} &lt; 265\text{m}\Omega</math> (<math>V_{GS} = -2.5\text{V}</math>)</p>

TSOP6  
Top View



#### Absolute Maximum Ratings $T_A=25^\circ\text{C}$ unless otherwise noted

Parameter	Symbol	Maximum	Units
Drain-Source Voltage	$V_{DS}$	-30	V
Gate-Source Voltage	$V_{GS}$	$\pm 12$	V
Continuous Drain Current <sup>A</sup>	$I_D$	-2.3	A
$T_A=70^\circ\text{C}$		-1.8	
Pulsed Drain Current <sup>B</sup>	$I_{DM}$	-20	
Power Dissipation <sup>A</sup>	$P_D$	1.15	W
$T_A=70^\circ\text{C}$		0.73	
Junction and Storage Temperature Range	$T_J, T_{STG}$	-55 to 150	°C

#### Thermal Characteristics

Parameter	Symbol	Typ	Max	Units
Maximum Junction-to-Ambient <sup>A</sup>	$R_{\theta JA}$	78	110	°C/W
Steady-State		106	150	°C/W
Maximum Junction-to-Lead <sup>C</sup>	$R_{\theta JL}$	64	80	°C/W

**Electrical Characteristics ( $T_J=25^\circ\text{C}$  unless otherwise noted)**

Symbol	Parameter	Conditions	Min	Typ	Max	Units
<b>STATIC PARAMETERS</b>						
$\text{BV}_{\text{DSS}}$	Drain-Source Breakdown Voltage	$I_D=-250\mu\text{A}$ , $V_{GS}=0\text{V}$	-30			V
$I_{\text{DSS}}$	Zero Gate Voltage Drain Current	$V_{DS}=-24\text{V}$ , $V_{GS}=0\text{V}$	$T_J=55^\circ\text{C}$	-1	-5	$\mu\text{A}$
$I_{\text{GSS}}$	Gate-Body leakage current	$V_{DS}=0\text{V}$ , $V_{GS}=\pm 12\text{V}$			$\pm 100$	nA
$V_{GS(\text{th})}$	Gate Threshold Voltage	$V_{DS}=V_{GS}$ , $I_D=-250\mu\text{A}$	-0.6	-1	-1.4	V
$I_{D(\text{ON})}$	On state drain current	$V_{GS}=-4.5\text{V}$ , $V_{DS}=-5\text{V}$	-20			A
$R_{DS(\text{ON})}$	Static Drain-Source On-Resistance	$V_{GS}=-10\text{V}$ , $I_D=-2.3\text{A}$	$T_J=125^\circ\text{C}$	107	135	$\text{m}\Omega$
		$V_{GS}=-4.5\text{V}$ , $I_D=-2\text{A}$		135	185	
		$V_{GS}=-2.5\text{V}$ , $I_D=-1\text{A}$		195	265	
$g_{FS}$	Forward Transconductance	$V_{DS}=-5\text{V}$ , $I_D=-2.3\text{A}$		8		S
$V_{SD}$	Diode Forward Voltage	$I_S=-1\text{A}$ , $V_{GS}=0\text{V}$		-0.85	-1	V
$I_S$	Maximum Body-Diode Continuous Current				-1.35	A
<b>DYNAMIC PARAMETERS</b>						
$C_{iss}$	Input Capacitance	$V_{GS}=0\text{V}$ , $V_{DS}=-15\text{V}$ , $f=1\text{MHz}$		409		pF
$C_{oss}$	Output Capacitance			55		pF
$C_{rss}$	Reverse Transfer Capacitance			42		pF
$R_g$	Gate resistance	$V_{GS}=0\text{V}$ , $V_{DS}=0\text{V}$ , $f=1\text{MHz}$		12		$\Omega$
<b>SWITCHING PARAMETERS</b>						
$Q_g$	Total Gate Charge	$V_{GS}=-4.5\text{V}$ , $V_{DS}=-15\text{V}$ , $I_D=-2.0\text{A}$		4.9		nC
$Q_{gs}$	Gate Source Charge			0.6		nC
$Q_{gd}$	Gate Drain Charge			1.6		nC
$t_{D(\text{on})}$	Turn-On Delay Time	$V_{GS}=-10\text{V}$ , $V_{DS}=-15\text{V}$ , $R_L=7.5\Omega$ , $R_{\text{GEN}}=3\Omega$		6.9		ns
$t_r$	Turn-On Rise Time			3.3		ns
$t_{D(\text{off})}$	Turn-Off Delay Time			38.5		ns
$t_f$	Turn-Off Fall Time			13.2		ns
$t_{rr}$	Body Diode Reverse Recovery Time	$I_F=-2.0\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$		15		ns
$Q_{rr}$	Body Diode Reverse Recovery Charge	$I_F=-2.0\text{A}$ , $dI/dt=100\text{A}/\mu\text{s}$		8		nC

A: The value of  $R_{\theta JA}$  is measured with the device mounted on 1in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The value in any given application depends on the user's specific board design. The current rating is based on the  $t \leq 10\text{s}$  thermal resistance rating.

B: Repetitive rating, pulse width limited by junction temperature.

C. The  $R_{\theta JA}$  is the sum of the thermal impedance from junction to lead  $R_{\theta JL}$  and lead to ambient.

D. The static characteristics in Figures 1 to 6,12,14 are obtained using 80 $\mu\text{s}$  pulses, duty cycle 0.5% max.

E. These tests are performed with the device mounted on 1 in<sup>2</sup> FR-4 board with 2oz. Copper, in a still air environment with  $T_A=25^\circ\text{C}$ . The SOA curve provides a single pulse rating.

## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS

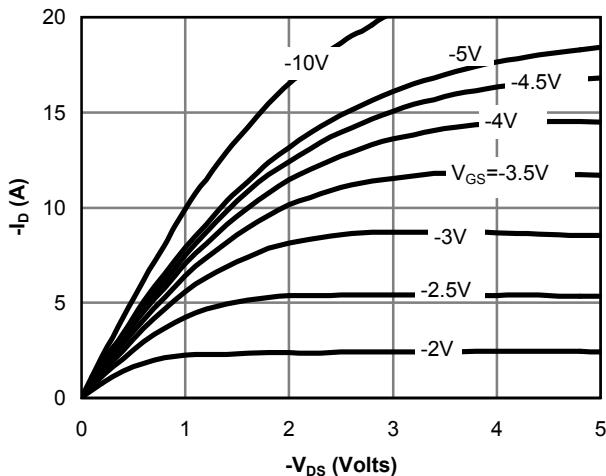


Fig 1: On-Region Characteristics

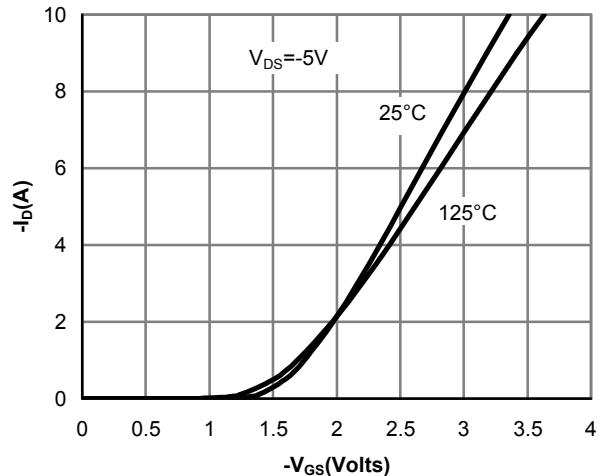


Figure 2: Transfer Characteristics

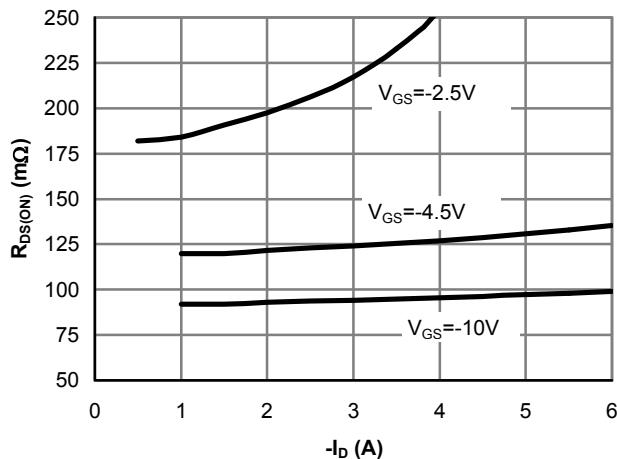


Figure 3: On-Resistance vs. Drain Current and Gate Voltage

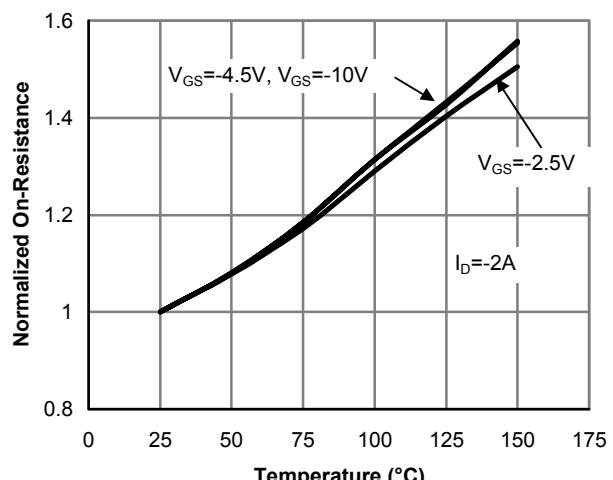


Figure 4: On-Resistance vs. Junction Temperature

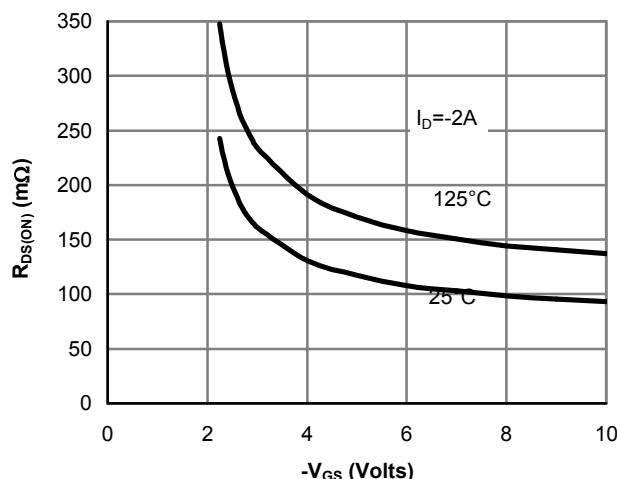


Figure 5: On-Resistance vs. Gate-Source Voltage

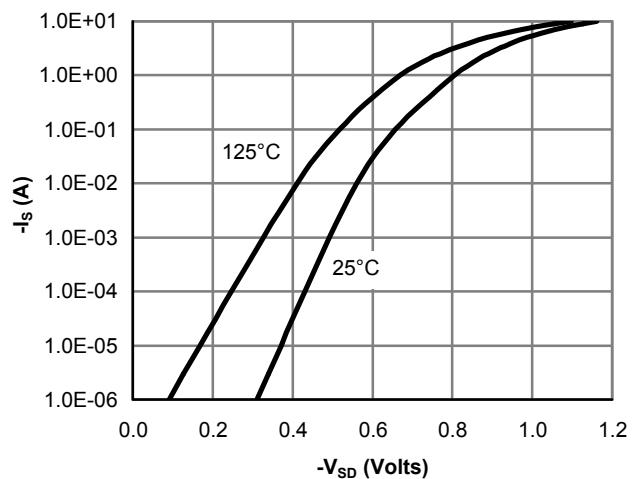
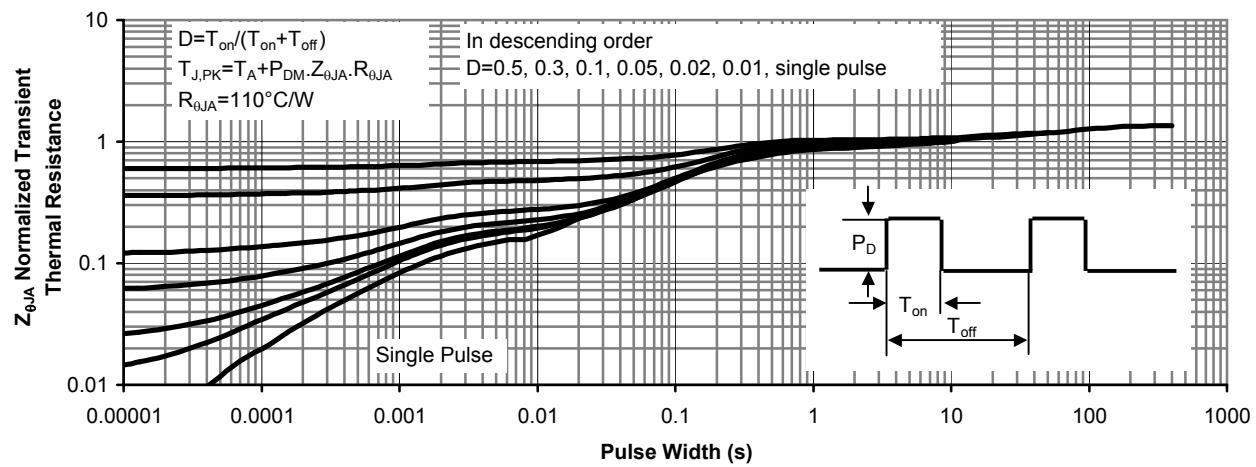
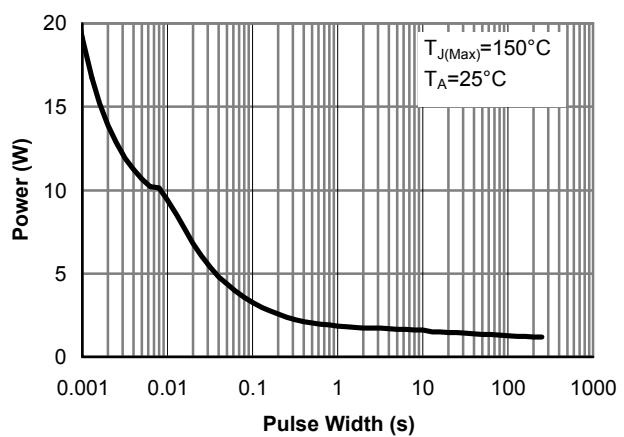
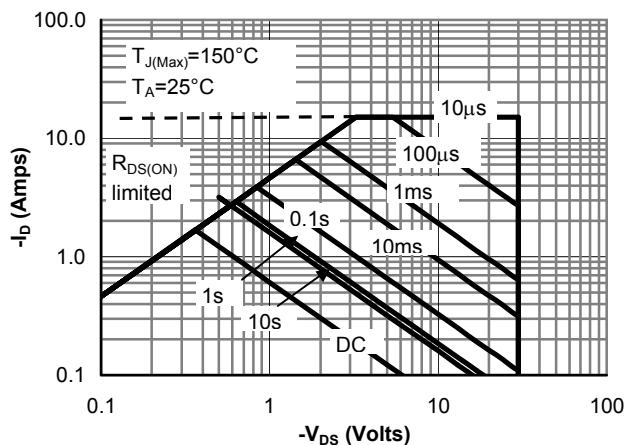
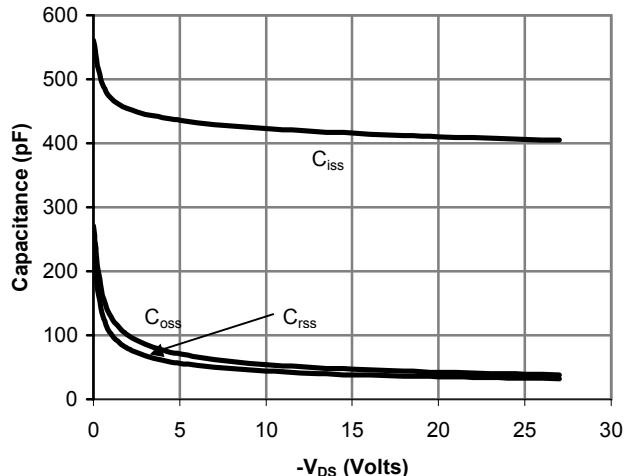
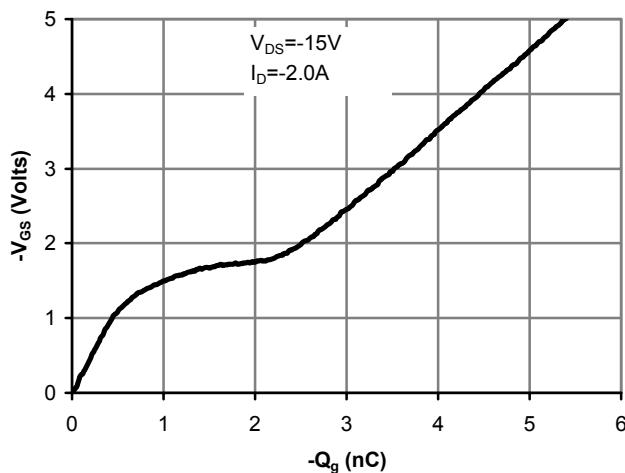


Figure 6: Body-Diode Characteristics

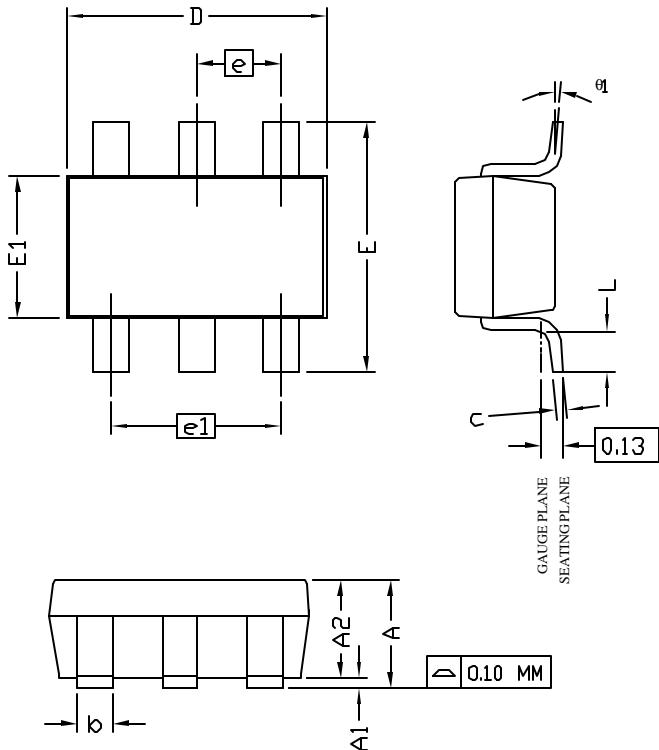
## TYPICAL ELECTRICAL AND THERMAL CHARACTERISTICS





**ALPHA & OMEGA**  
SEMICONDUCTOR, INC.

## TSOP-6 Package Data

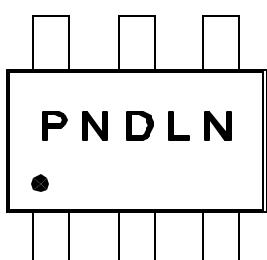


SYMBOLS	DIMENSIONS IN MILLIMETERS		
	MIN	NOM	MAX
A	1.00	—	1.25
A1	0.00	—	0.10
A2	1.00	1.10	1.15
b	0.35	0.40	0.50
c	0.10	0.13	0.20
D	2.70	2.90	3.10
E	2.60	2.80	3.00
E1	1.60	1.80	2.00
e	0.95 BSC		
e1	1.90 BSC		
L	0.37	—	—
θ1	1°	5°	8°

NOTE:

1. LEAD FINISH: 150 MICROINCHES ( 3.8 um) MIN.  
THICKNESS OF Tin/Lead (SOLDER) PLATED ON LEAD
2. TOLERANCE ±0.100 mm (4 mil) UNLESS OTHERWISE SPECIFIED
3. COPLANARITY : 0.1000 mm
4. DIMENSION L IS MEASURED IN GAGE PLANE

### PACKAGE MARKING DESCRIPTION

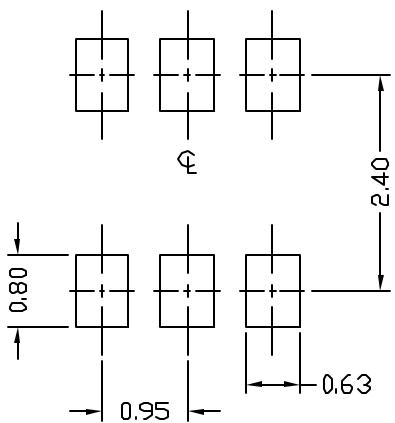


#### TSOP-6 PART NO. CODE

PART NO.	CODE
AO6801	H1

NOTE:  
P N - PART NUMBER CODE.  
D - YEAR AND WEEK CODE.  
L N - ASSEMBLY LOT CODE, FAB AND ASSEMBLY LOCATION CODE.

### RECOMMENDED LAND PATTERN

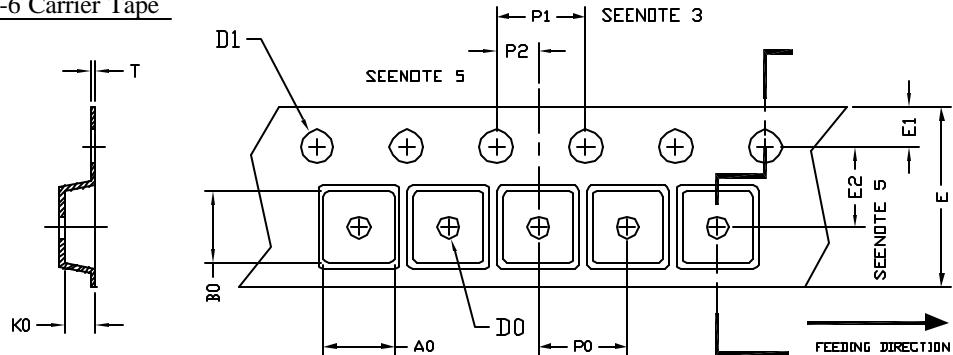




**ALPHA & OMEGA**  
SEMICONDUCTOR, INC.

## TSOP-6 Tape and Reel Data

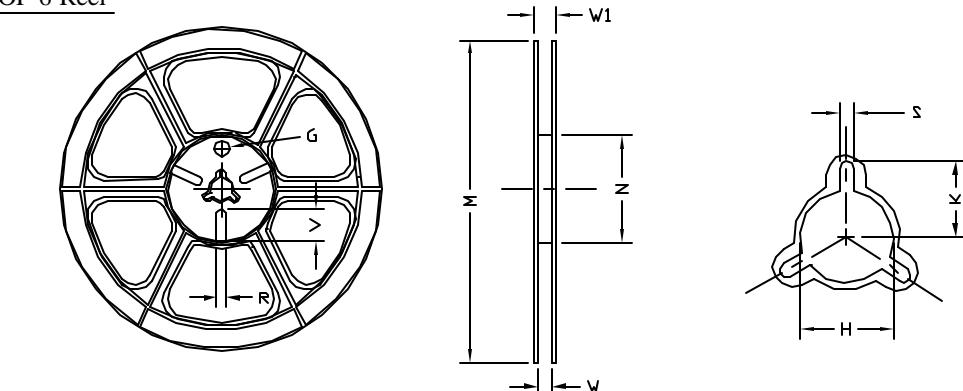
### TSOP-6 Carrier Tape



UNIT: MM

PACKAGE	A0	B0	K0	D0	D1	E	E1	E2	P0	P1	P2	T
SOT-23 (8 mm)	3.15 $\pm 0.10$	3.27 $\pm 0.10$	1.34 $\pm 0.10$	1.10 $\pm 0.01$	1.50 $\pm 0.10$	8.00 $\pm 0.20$	1.75 $\pm 0.10$	3.50 $\pm 0.05$	4.00 $\pm 0.10$	4.00 $\pm 0.10$	2.00 $\pm 0.10$	0.25 $\pm 0.05$

### TSOP-6 Reel



UNIT: MM

TAPE SIZE	REEL SIZE	M	N	W	W1	H	K	S	G	R	V
8 mm	Ø180	Ø180.00 $\pm 0.50$	Ø60.50	9.00 $\pm 0.30$	11.40 $\pm 1.00$	Ø13.00 $\pm 0.50$ $-0.20$	10.60	2.00 $\pm 0.50$	Ø9.00	5.00	18.00

### TSOP-6 Tape

Leader / Trailer  
& Orientation

